

FDP032N08 N-Channel PowerTrench[®] MOSFET 75 V, 235 A, 3.2 m Ω

Features

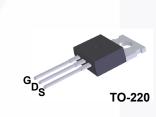
- $R_{DS(on)}$ = 2.5 m Ω (Typ.) @ V_{GS} = 10 V, I_D = 75 A
- · Fast Switching Speed
- Low Gate Charge
- High Performance Trench Technology for Extremely Low $\mathsf{R}_{\mathsf{DS}(\mathsf{on})}$
- High Power and Current Handling Capability
- RoHS Compliant

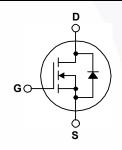
Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench[®] process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

Applications

- Synchronous Rectification for ATX / Server / Telecom PSU
- · Battery Protection Circuit
- Motor Drives and Uninterruptible Power Supplies





MOSFET Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		Parameter		FDP032N08	Unit
V _{DSS}	Drain to Source Voltage			75	V
V _{GSS}	Gate to Source Voltage			±20	V
	Drain Current -	Continuous (T _C = 25°C, Sili	con Limited)	235	Α
ID		con Limited)	165	Α	
	-	ckage Limited)	120	Α	
I _{DM}	Drain Current	- Pulsed	(Note 1)	940	Α
E _{AS}	Single Pulsed Avalanche Energy			1995	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		(Note 3)	6.0	V/ns
P _D	Dower Dissinction	(T _C = 25 ^o C)		375	W
	Power Dissipation	- Derate Above 25°C	- Derate Above 25°C		W/ºC
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +175	°C
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300	°C

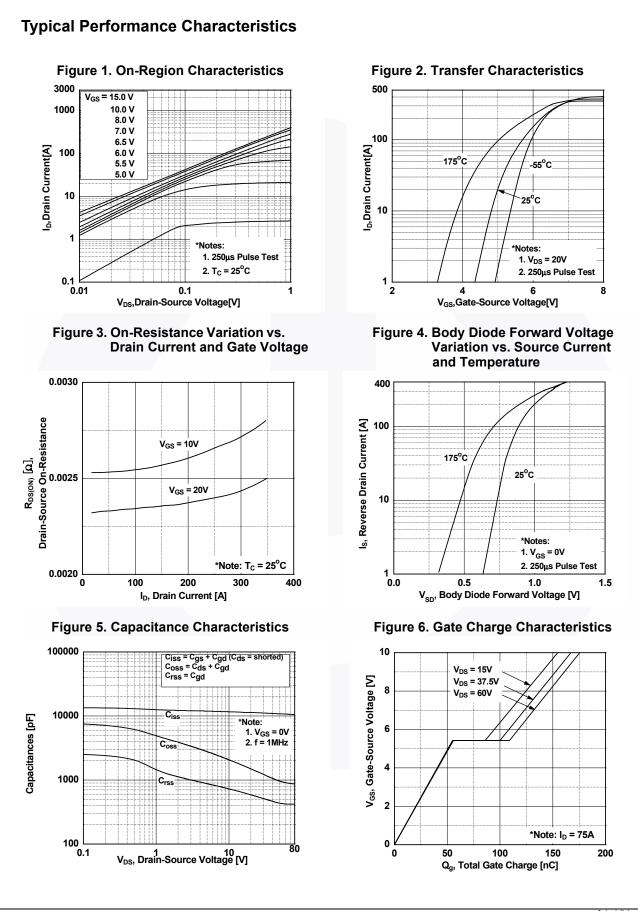
Thermal Characteristics

Symbol	Parameter	FDP032N08	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	0.4	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	°C/vv

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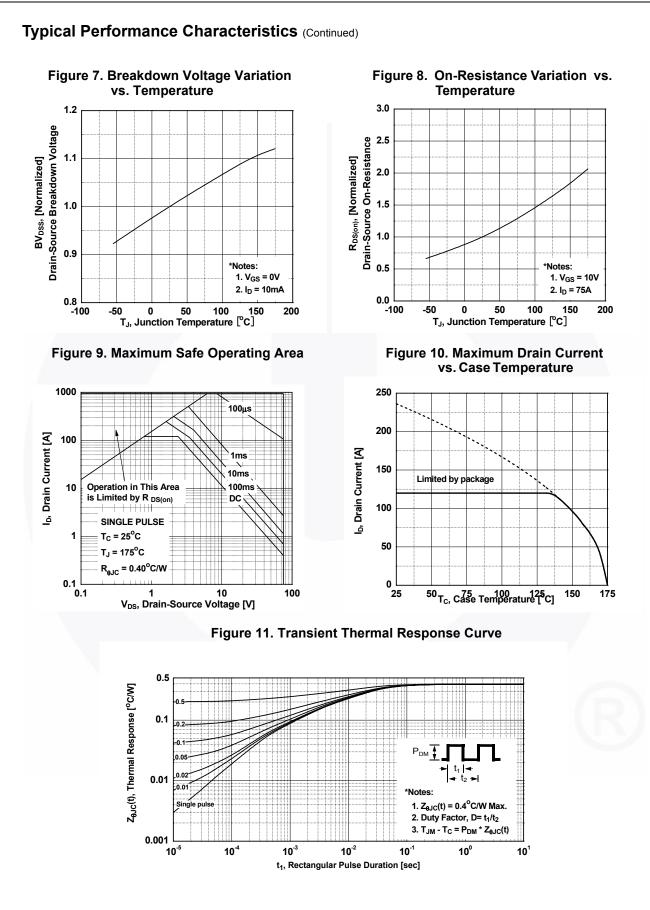
November 2013

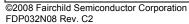
		Packag	e Packing Method	Reel Size	Тар	e Width	Qua	ntity	
		TO-220) Tube	N/A		N/A	50 units		
lectrica	l Chara	acteristics T _c =	25°C unless	otherwise noted					
Symbol		Parameter		Test Conditio	ons	Min.	Тур.	Max.	Unit
Off Charac	teristics						.,,,,		
BV _{DSS}	Drain to Source Breakdown Voltage Breakdown Voltage Temperature Coefficient		Itage	$I_D = 250 \mu$ A, V _{GS} = 0 V, T _C = 25 ^o C $I_D = 250 \mu$ A, Referenced to 25 ^o C		75	_	-	V
ΔBV _{DSS} /ΔT _J			-			-	0.05	-	V/ºC
DSS	Zero Ga	Gate Voltage Drain Current		$V_{DS} = 75 V, V_{GS} = 0 V$ $V_{DS} = 75 V, T_{C} = 150^{\circ}C$		-	-	1 500	μA
GSS	Gate to I	Body Leakage Current		$V_{\rm GS} = \pm 20 \text{ V}, V_{\rm DS} = 0 \text{ V}$		-	-	±100	nA
On Charac	teristics								
GS(th)	-	reshold Voltage		V _{GS} = V _{DS} , I _D = 250 μA	4	2.5	3.5	4.5	V
R _{DS(on)}		ain to Source On Resi	stance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 75 \text{ A}$		-	2.5	3.2	mΩ
FS		Transconductance		$V_{\rm DS}$ = 10 V, I _D = 75 A		-	180	-	S
Dynamic C	haracte	ristics							
C _{iss}		pacitance		V _{DS} = 25 V, V _{GS} = 0 V,		-	11400	15160	pF
C _{oss}		apacitance				-	1360	1810	pF
Crss		Transfer Capacitance		_f = 1 MHz	-	-	595	800	pF
Q _{g(tot)}		te Charge at 10V		$V_{} = 60 V_{} = 75 A_{}$		-	169	220	nC
Q_{gs}		Source Gate Charge		V _{DS} = 60 V, I _D = 75 A, V _{GS} = 10 V		-	60	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			(Note 4)		-	47	-	nC
Switching	Charact	eristics							
t _{d(on)}		Delay Time				-	230	470	ns
r		Rise Time		V _{DD} = 37.5 V, I _D = 75 A	λ,	-	191	392	ns
t _{d(off)}		Delay Time		$R_{\rm G} = 25 \Omega, V_{\rm GS} = 10 V$ (Note 4)			335	680	ns
t _f		Fall Time				-	121	252	ns
Drain-Sou	rce Diod	e Characteristics			L				
s	1	n Continuous Drain to S		e Forward Current		-	_	235	Α
		n Pulsed Drain to Sour			-	_	940	A	
I _{SM} V _{SD}						-	-	1.3	V
		Drain to Source Diode Forward Voltage		$V_{GS} = 0 V, I_{SD} = 75 A$					ns
								nC	
	Reverse g: pulse-width li $_{S}$ = 75 A, V _{DD}	Recovery Time Recovery Charge mited by maximum junction te = 50 V, R _G = 25 Ω , starting T _J DD \leq BV _{DSS} , starting T _J = 25°C	= 25°C.	V _{GS} = 0 V, I _{SD} = 75 A, dI _F /dt = 100 A/μs	-	-	53 77	-	

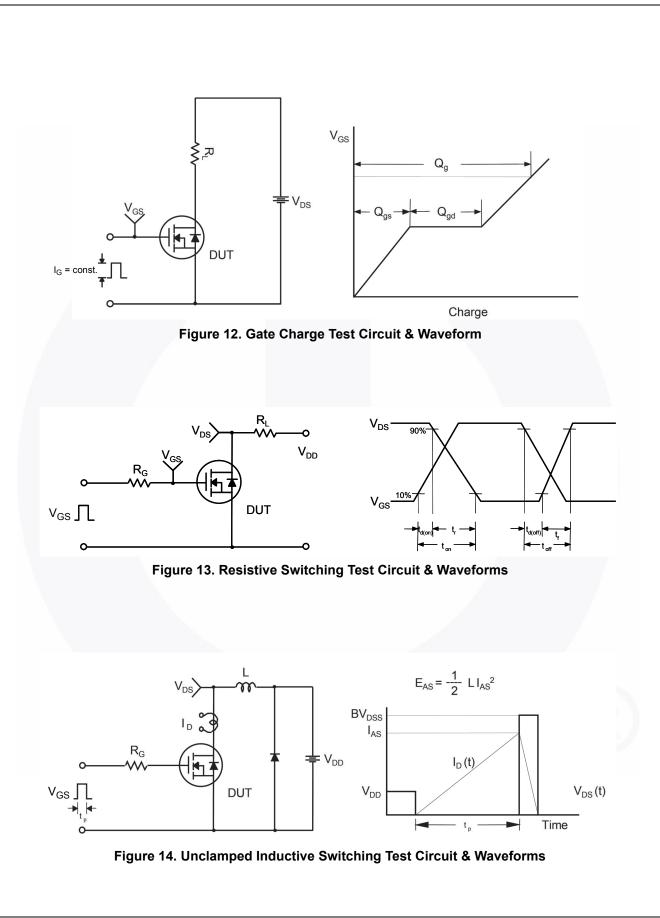


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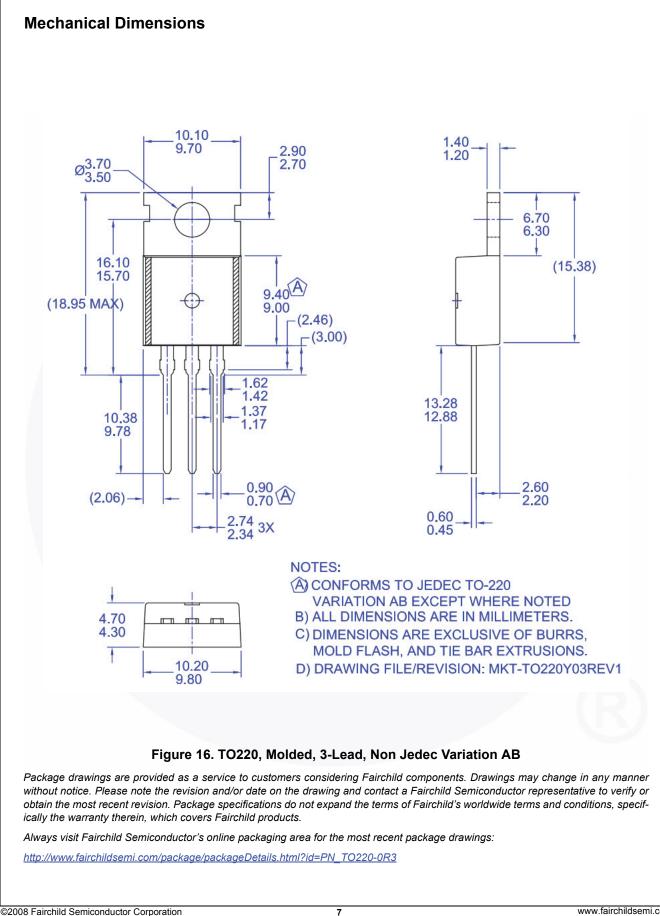






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DUT + v_{DS} a ۱_{SD} م L Driver R_G, Same Type as DUT L F ∨_{DD} $\prod V_{GS}$ • dv/dt controlled by R_G • I_{SD} controlled by pulse period Î Gate Pulse Width V_{GS} D = Gate Pulse Period 10V (Driver) I_{FM}, Body Diode Forward Current I _{SD} di/dt (DUT) I_{RM} Body Diode Reverse Current V_{DS} (DUT) Body Diode Recovery dv/dt V_{SD} V_{DD} Body Diode Forward Voltage Drop Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



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